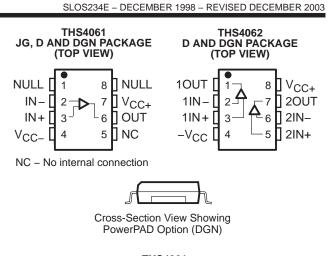
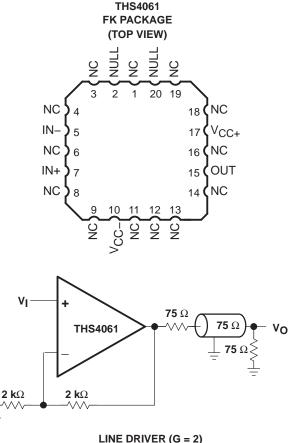
High Speed

- 180 MHz Bandwidth (G = 1, -3 dB)
- 400 V/us Slew Rate
- 40-ns Settling Time (0.1%)
- High Output Drive, I_O = 115 mA (typ)
- Excellent Video Performance
 - 75 MHz 0.1 dB Bandwidth (G = 1)
 - 0.02% Differential Gain
 - 0.02° Differential Phase
- Very Low Distortion
 THD = -72 dBc at f = 1 MHz
- Wide Range of Power Supplies
 V_{CC} = ±5 V to ±15 V
- Available in Standard SOIC, MSOP PowerPAD[™], JG, or FK Package
- Evaluation Module Available

description

The THS4061 and THS4062 are generalpurpose, single/dual, high-speed voltage feedback amplifiers ideal for a wide range of applications including video, communication, and imaging. The devices offer very good ac performance with 180-MHz bandwidth, 400-V/µs slew rate, and 40-ns settling time (0.1%). The THS4061/2 are stable at all gains for both inverting and noninverting configurations. These amplifiers have a high output drive capability of 115 mA and draw only 7.8 mA supply current per channel. Excellent professional video results can be obtained with the low differential gain/phase errors of 0.02%/0.02° and wide 0.1 db flatness to 75 MHz. For applications requiring low distortion, the THS4061/2 is ideally suited with total harmonic distortion of -72 dBc at f = 1 MHz.







CAUTION: The THS4061 and THS4062 provide ESD protection circuitry. However, permanent damage can still occur if this device is subjected to high-energy electrostatic discharges. Proper ESD precautions are recommended to avoid any performance degradation or loss of functionality



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments Incorporated.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 1998 – 2003, Texas Instruments Incorporated On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

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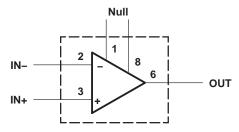
	RELATED DEVICES
DEVICE	DESCRIPTION
THS4011/2	290-MHz Low Distortion High-Speed Amplifiers
THS4031/2	100-MHz Low Noise High Speed-Amplifiers
THS4061/2	180-MHz High-Speed Amplifiers

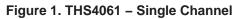
AVAILABLE OPTIONS

			PACKAGED	DEVICES	_		
TA	NUMBER OF CHANNELS	PLASTIC SMALL OUTLINE [†] (D)	PLASTIC MSOP† (DGN)	CERAMIC DIP (JG)	CHIP CARRIER (FK)	MSOP SYMBOL	EVALUATION MODULES
0°C to	1	THS4061CD	THS4061CDGN	—	—	TIABS	THS4061EVM
70°C	2	THS4062CD	THS4062CDGN	—	—	TIABM	THS4062EVM
-40°C to	1	THS4061ID	THS4061IDGN	—	_	TIABT	—
85°C	2	THS4062ID	THS4062IDGN	—	_	TIABN	—
–55°C to 125°C	1	_	_	THS4061MJG	THS4061MFK	_	—

[†] The D and DGN packages are available taped and reeled. Add an R suffix to the device type (i.e., THS4061CDGNR).

functional block diagram





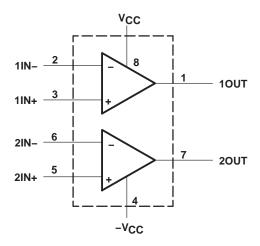


Figure 2. THS4062 – Dual Channel



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Input voltage, V _I Output current, I _O					
	C-suffix 0°C to 70°C I-suffix -40°C to 85°C M-suffix -55°C to 125°C				
Storage temperature, T _{stg} -65°C to 150° Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds, D and DGN package 300° Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds, JG package 300° Case temperature for 60 seconds, FK package 260°					

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	7 · · · · · · · · · · · · · · · · · · ·		T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	740 mW	6 mW/°C	475 mW	385 mW	—
DGN [‡]	2.14 W	17.1 mW/°C	1.37 W	1.11 W	—
JG	1057 mW	8.4 mW/°C	627 mW	546 mW	210 mW
FK	1375 mW	11 mW/°C	880 mW	715 mW	275 mW

[‡] The DGN package incorporates a PowerPAD on the underside of the device. This acts as a heatsink and must be connected to a thermal dissipation plane for proper power dissipation. Failure to do so can result in exceeding the maximum specified junction temperature, which could permanently damage the device.

recommended operating conditions

		MIN	NOM MAX	UNIT
	Dual supply	±4.5	±16	
Supply voltage, V _{CC} + and V _{CC} -	Single supply	9	32	V
	C-suffix	0	70	
Operating free-air temperature, T _A	I-suffix	-40	85	°C
	M-suffix	-55	125	



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electrical characteristics at T_A = 25°C, V_{CC} = ± 15 V, R_L = 150 Ω (unless otherwise noted)

dynamic performance

	PARAMETER	TEST CONDITIONS [†]			THS4061C/I, THS4062C/I			
					TYP	MAX		
		$V_{CC} = \pm 5 V$	Gain = 1		180		MHz	
	Dynamic performance small-signal bandwidth (-3 dB)	$V_{CC} = \pm 15 V$			50		N 41 1-	
BW		$V_{CC} = \pm 5 V$	Gain = -1		50		MHz	
	Bandwidth for 0.1 dB flatness	$V_{CC} = \pm 15 V$			75		N 41 1-	
		$V_{CC} = \pm 5 V$	Gain = 1		20		MHz	
0.0		$V_{CC} = \pm 15 V$			400		· V/μs	
SR	Slew rate	$V_{CC} = \pm 5 V$	Gain = -1		350			
		$V_{CC} = \pm 15 \text{ V}, 5 \text{-V step } (0 \text{ V to } 5 \text{ V})$			40			
	Settling time to 0.1%	$V_{CC} = \pm 5 \text{ V}, \qquad V_{O} = -2.5 \text{ V to } 2.5 \text{ V},$	Gain = -1		40		ns	
t _s		$V_{CC} = \pm 15 \text{ V}, 5\text{-V step } (0 \text{ V to 5 V})$			140		ns	
	Settling time to 0.01%	$V_{CC} = \pm 5 \text{ V}, \qquad V_{O} = -2.5 \text{ V to } 2.5 \text{ V},$	Gain = -1		150			

[†] Full range = 0° C to 70° C for C suffix and -40° C to 85° C for I suffix

noise/distortion performance

	PARAMETER	TEST CONDITIONS [†]			THS4061C/I, THS4062C/I			UNIT
							MAX	
THD	Total harmonic distortion	f = 1 MHz				-72		dBc
Vn	Input voltage noise	f = 10 kHz,	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$			14.5		nV/√Hz
In	Input current noise	f = 10 kHz,	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$			1.6		pA/√Hz
	D			V _{CC} = ±15 V		0.02 %		
	Differential gain error	Gain = 2,	NTSC, 40 IRE modulation			0.02 %		
	D."			V _{CC} = ±15 V		0.02°		
	Differential phase error	Gain = 2,	NTSC, 40 IRE modulation	IRE modulation $V_{CC} = \pm 5 V$		0.06°		
	Channel-to-channel crosstalk (THS4062 only)	V _{CC} = ±5 V c	or ±15 V, f = 1 MHz			65		dB

[†] Full range = 0°C to 70°C for C suffix and –40°C to 85°C for I suffix

dc performance

PARAMETER		TEST CONDITIONS [†]	TEST CONDITIONS [†]			THS4061C/I, THS4062C/I		
				MIN	TYP	MAX		
			T _A = 25°C	5	15			
	On an Ison and a	$V_{CC} = \pm 15 \text{ V}, V_O = \pm 10 \text{ V}, R_L = 1 \text{ k}\Omega$	T _A = full range	4			V/mV	
	Open loop gain		T _A = 25°C	2.5	8			
		$V_{CC} = \pm 5 \text{ V}, V_O = \pm 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$	T _A = full range	2			V/mV	
	Input offset voltage	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$			2.5	8	mV	
Vos	Offset drift	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$T_A = $ full range		15		μV/°C	
I _{IB}	Input bias current	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	T _A = full range		3	6	μA	
IOS	Input offset current	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	T _A = full range		75	250	nA	
	Offset current drift	T _A = full range			0.3		nA/∘C	

[†] Full range = 0° C to 70° C for C suffix and -40° C to 85° C for I suffix



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electrical characteristics at T_A = 25°C, V_{CC} = \pm 15 V, R_L = 150 Ω (unless otherwise noted) (continued)

input characteristics

	PARAMETER		TEST CONDITIONS [†]			THS4061C/I, THS4062C/I		
					MIN	TYP	MAX	
		$V_{CC} = \pm 15 V$			±13.8	±14.1		
VICR	Common-mode input voltage range	$V_{CC} = \pm 5 V$			±3.8	±4.3		V
		$V_{CC} = \pm 15 V,$	$V_{ICR} = \pm 12 V$	T _A = full range	70	110		dB
CMRR	Common mode rejection ratio	$V_{CC} = \pm 5 V$,	VICR = ±2.5 V		70	95		
RI	Input resistance					1		MΩ
Ci	Input capacitance					2		pF

[†] Full range = 0°C to 70°C for C suffix and -40°C to 85°C for I suffix

output characteristics

PARAMETER		TEST CONDITIONS [†]			THS4061C/I, THS4062C/I		
				MIN	TYP	MAX	
VO Output voltage swing	$V_{CC} = \pm 15 V$	$R_L = 250 \ \Omega$	±11.5	±12.5			
		$V_{CC} = \pm 5 V$	RL = 150 Ω	±3.2	±3.5		V
	Output voltage swing	$V_{CC} = \pm 15 V$	R _L = 1 kΩ	±13	±13.5		v
		$V_{CC} = \pm 5 V$		±3.5	±3.7		
		$V_{CC} = \pm 15 V$	_	80	115		
10	Output current	$V_{CC} = \pm 5 V$	R _L = 20 Ω	50	75		mA
ISC	Short-circuit current	$V_{CC} = \pm 15 V$			150		mA
RO	Output resistance	Open loop			12		Ω

[†] Full range = 0°C to 70°C for C suffix and -40° C to 85°C for I suffix

power supply

	PARAMETER	TEST CONDITIONS [†]			THS4061C/I, THS4062C/I			
				MIN	TYP	MAX		
		Dual supply		±4.5		±16.5	V	
VCC	Supply voltage operating range	Single supply				33	v	
		$V_{CC} = \pm 15 V$	T full searce		7.8	10.5	mA	
lcc	Quiescent current (per amplifier)	$V_{CC} = \pm 5 V$	T _A = full range		7.3	10		
DODD	Device events relief retie		$T_A = 25^{\circ}C$	70 78	78		-ID	
PSRR	Power supply rejection ratio	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	T _A = full range	68			dB	

[†] Full range = 0°C to 70°C for C suffix and -40°C to 85°C for I suffix



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electrical characteristics at T_A = 25°C, V_{CC} = ± 15 V, R_L = 150 Ω (unless otherwise noted)

dynamic performance

			TEST CONDITIONS [†]		TF				
	PARAMETER		TEST CONDITIONS			TYP	MAX	UNIT	
	Unity-gain bandwidth	Closed loop,	$R_L = 1 k\Omega$	$V_{CC} = \pm 15 V$	*140	180		MHz	
BW		$V_{CC} = \pm 15 V$		Coin 1		180		N 41 I	
	Dynamic performance small-signal	$V_{CC} = \pm 5 V$		Gain = 1		180		MHz	
	bandwidth (-3 dB)	$V_{CC} = \pm 15 V$				50			
		$V_{CC} = \pm 5 V$		Gain = –1		50		MHz	
		$V_{CC} = \pm 15 V$				75			
	Bandwidth for 0.1 dB flatness	$V_{CC} = \pm 5 V$		Gain = 1		20		MHz	
SR	Slew rate	$V_{CC} = \pm 15 V$	$R_L = 1 k\Omega$		*400	500		V/µs	
		$V_{CC} = \pm 15 V,$	5-V step (0 V to 5 V)			40		ns	
	Settling time to 0.1%	$V_{CC} = \pm 5 V,$	$V_{O} = -2.5 \text{ V} \text{ to } 2.5 \text{ V},$	Gain = -1		40			
t _s		$V_{CC} = \pm 15 V,$	5-V step (0 V to 5 V)	Coin 1		140		ns	
	Settling time to 0.01%	$V_{CC} = \pm 5 V,$	V_{O} = -2.5 V to 2.5 V,	Gain = -1		150			

[†] Full range = -55° C to 125° C for M suffix

*This parameter is not tested.

noise/distortion performance

				Tŀ	Λ	UNIT		
	PARAMETER		TEST CONDITIONS [†]	MIN	TYP	MAX	UNIT	
THD	Total harmonic distortion	f = 1 MHz				-72		dBc
Vn	Input voltage noise	f = 10 kHz,	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$			14.5		nV/√Hz
۱ _n	Input current noise	f = 10 kHz,	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$			1.6		pA/√Hz
	Differential agin arman			$V_{CC} = \pm 15 V$		0.02		0/
	Differential gain error	Gain = 2,	NTSC, 40 IRE Modulation	$V_{CC} = \pm 5 V$		0.02		%
	Differential phase error		NTSC 40 IRE Modulation	$V_{CC} = \pm 15 V$		0.02°		
	Differential priase error	Gain = 2,	Gain = 2, NTSC, 40 IRE Modulation			0.06°		

[†] Full range = -55° C to 125° C for M suffix

dc performance

	PARAMETER	TERT OF	TEST CONDITIONS [†]						
	PARAMETER	TEST CC	MIN	TYP	MAX	UNIT			
	On an Is an and	$V_{CC} = \pm 15 \text{ V}, V_{O} = \pm 10 \text{ V},$	$R_L = 1 \ k\Omega$	T (5	9			
	Open loop gain	$V_{CC} = \pm 5 \text{ V}, \qquad V_O = \pm 2.5 \text{ V}$, $R_L = 1 k\Omega$	$T_A = full range$	2.5	6		V/mV	
	long to offer a true lange		D 41-0	$T_A = 25^{\circ}C$		2.5	8	mV	
Vio	Input offset voltage	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$R_L = 1 k\Omega$	$T_A = full range$			9	mV	
	Offset drift	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$R_L = 1 \ k\Omega$	$T_A = full range$		15		μV/°C	
I _{IB}	Input bias current	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$R_L = 1 \ k\Omega$	$T_A = full range$		3	6	μΑ	
IIO	Input offset current	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$R_L = 1 \ k\Omega$	$T_A = full range$		75	250	nA	
	Offset current drift	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$R_L = 1 \ k\Omega$	$T_A = full range$		0.3		nA/∘C	

[†] Full range = -55° C to 125° C for M suffix



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electrical characteristics at T_A = full range, V_{CC} = \pm 15 V, R_L = 1 k Ω (unless otherwise noted) (continued)

input characteristics

DADAMETED	TEAT CONDITIONAT	Т	UNIT		
PARAMETER		MIN	TYP	MAX	UNIT
	$V_{CC} = \pm 15 V$	±13.8	±14.1		Ň
Common-mode input voltage range	$V_{CC} = \pm 5 V$	±3.8	±4.3		V
	$V_{CC} = \pm 15 \text{ V}, \qquad V_{ICR} = \pm 12 \text{ V}$	70	86		JD
Common mode rejection ratio	$V_{CC} = \pm 5 \text{ V}, \qquad V_{ICR} = \pm 2.5 \text{ V}$	80	90		dB
Input resistance			1		MΩ
Input capacitance			2		pF
	1	Common-mode input voltage range $V_{CC} = \pm 15 \text{ V}$ Common mode rejection ratio $V_{CC} = \pm 5 \text{ V}$ Voc = $\pm 15 \text{ V}$, $V_{ICR} = \pm 12 \text{ V}$ Voc = $\pm 5 \text{ V}$, $V_{ICR} = \pm 2.5 \text{ V}$ Input resistance	PARAMETERTEST CONDITIONS†Common-mode input voltage range $V_{CC} = \pm 15 V$ ± 13.8 $V_{CC} = \pm 5 V$ ± 3.8 $V_{CC} = \pm 5 V$ ± 3.8 $V_{CC} = \pm 15 V$, $V_{ICR} = \pm 12 V$ 70 $V_{CC} = \pm 5 V$, $V_{ICR} = \pm 2.5 V$ 80Input resistance $V_{CC} = \pm 5 V$, $V_{ICR} = \pm 2.5 V$	PARAMETERTEST CONDITIONS†MINTYPCommon-mode input voltage range $V_{CC} = \pm 15 V$ ± 13.8 ± 14.1 $V_{CC} = \pm 5 V$ ± 3.8 ± 4.3 Common mode rejection ratio $V_{CC} = \pm 15 V$, $V_{ICR} = \pm 12 V$ 7086 $V_{CC} = \pm 5 V$, $V_{ICR} = \pm 2.5 V$ 8090Input resistance1	MIN TYP MAX Common-mode input voltage range $V_{CC} = \pm 15 \text{ V}$ ± 13.8 ± 14.1 $V_{CC} = \pm 5 \text{ V}$ ± 3.8 ± 4.3 Common mode rejection ratio $V_{CC} = \pm 15 \text{ V}$, $V_{ICR} = \pm 12 \text{ V}$ 70 86 V_{CC} = \pm 5 \text{ V}, $V_{ICR} = \pm 2.5 \text{ V}$ 80 90 1

[†] Full range = -55° C to 125° C for M suffix

output characteristics

			Т	Λ	UNIT		
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
		$V_{CC} = \pm 15 V$	RL = 250 Ω	±12	±13.1		
		$V_{CC} = \pm 5 V$	RL = 150 Ω	±3.2	±3.5		V
VO	Output voltage swing	$V_{CC} = \pm 15 V$	D (1)0	±13	±13.5		
		$V_{CC} = \pm 5 V$	R _L = 1 kΩ	±3.5	±3.7		V
		$V_{CC} = \pm 15 V$	D	70	115		
10	Output current	$V_{CC} = \pm 5 V$	R _L = 20 Ω	50	75		mA
ISC	Short-circuit current	$V_{CC} = \pm 15 V$	$T_A = 25^{\circ}C$		150		mA
RO	Output resistance	Open loop			12		Ω

[†]Full range = -55° C to 125° C for M suffix

power supply

				TH	IS4061N	Л	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
N		Dual supply		±4.5		±16.5	N
VCC	Supply voltage operating range	Single supply		9		33	V
		$V_{CC} = \pm 15 V$	T. 0500		7.8	9	
I.		$V_{CC} = \pm 5 V$	T _A = 25°C		7.3	8.5	
ICC	Quiescent current	$V_{CC} = \pm 15 V$	T (1)			11	mA
		$V_{CC} = \pm 5 V$	T _A = full range			10.5	
PSRR	Bower supply rejection ratio		$T_A = 25^{\circ}C$	76	80		dB
FORK	SRR Power supply rejection ratio	$V_{CC} = \pm 5 V \text{ or } \pm 15 V$	$T_A = full range$	74	78		uБ

[†] Full range = -55° C to 125° C for M suffix

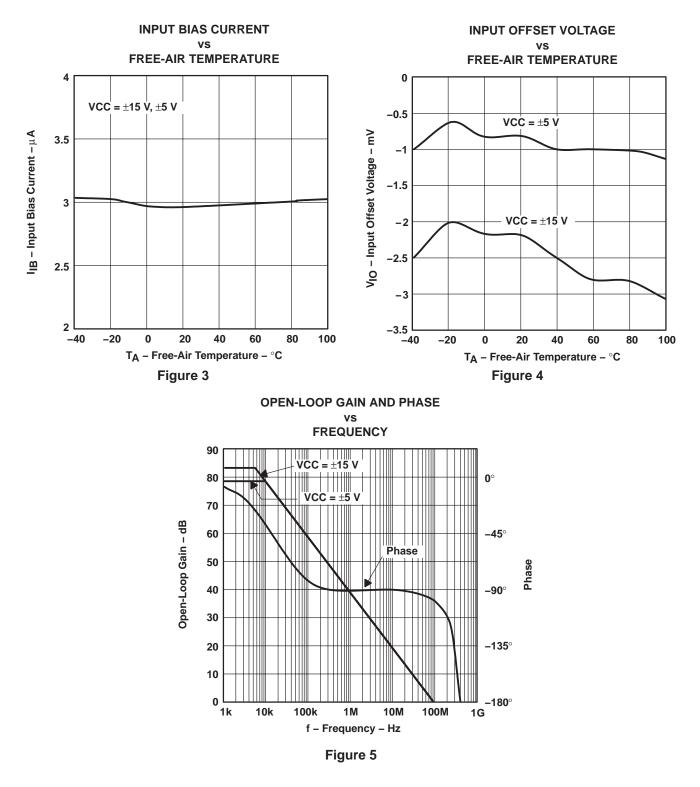


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			FIGURE
IIB	Input bias current	vs Free-air temperature	3
VIO	Input offset voltage	vs Free-air temperature	4
	Open-loop gain	vs Frequency	5
	Phase	vs Frequency	5
	Differential gain	vs Number of loads	6, 8
	Differential phase	vs Number of loads	7, 9
	Closed-loop gain	vs Frequency	10, 11
	Output amplitude	vs Frequency	12, 13
CMRR	Common-mode rejection ratio	vs Frequency	14
		vs Frequency	15
PSRR	Power supply rejection ratio	vs Free-air temperature	16
VO(PP)	Output voltage swing	vs Supply voltage	17
ICC	Supply current	vs Free-air temperature	18
Env	Noise spectral density	vs Frequency	19
THD	Total harmonic distortion	vs Frequency	20, 21
	Crosstalk	vs Frequency	22, 23

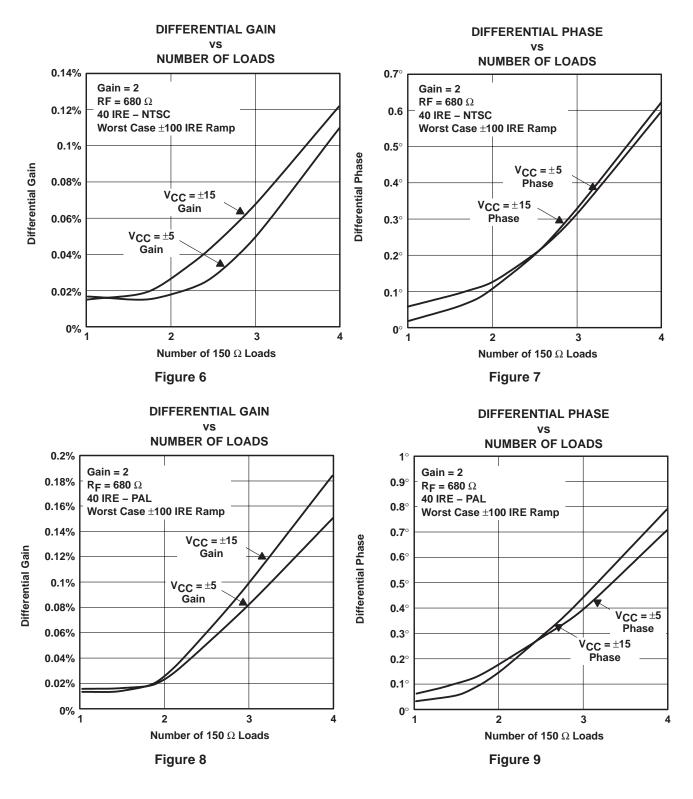


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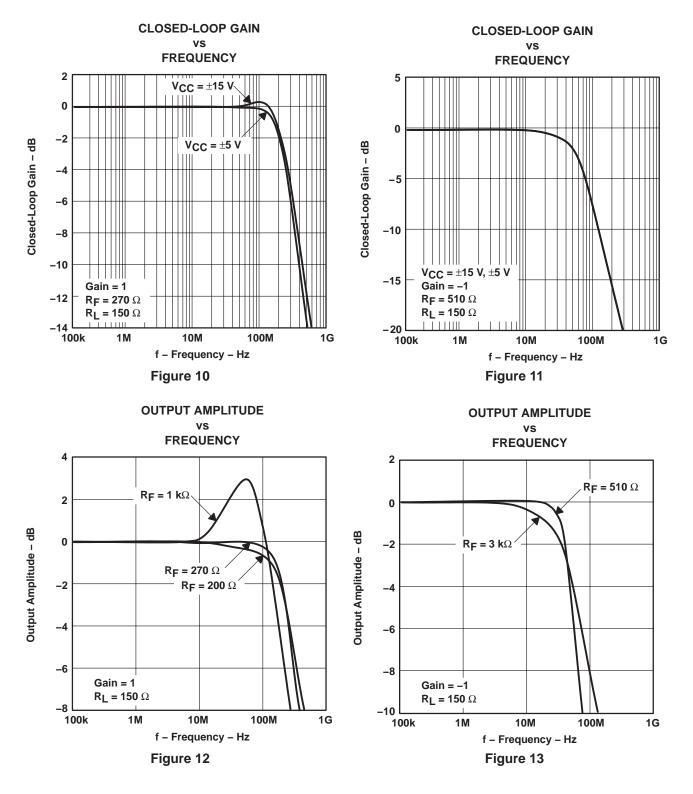


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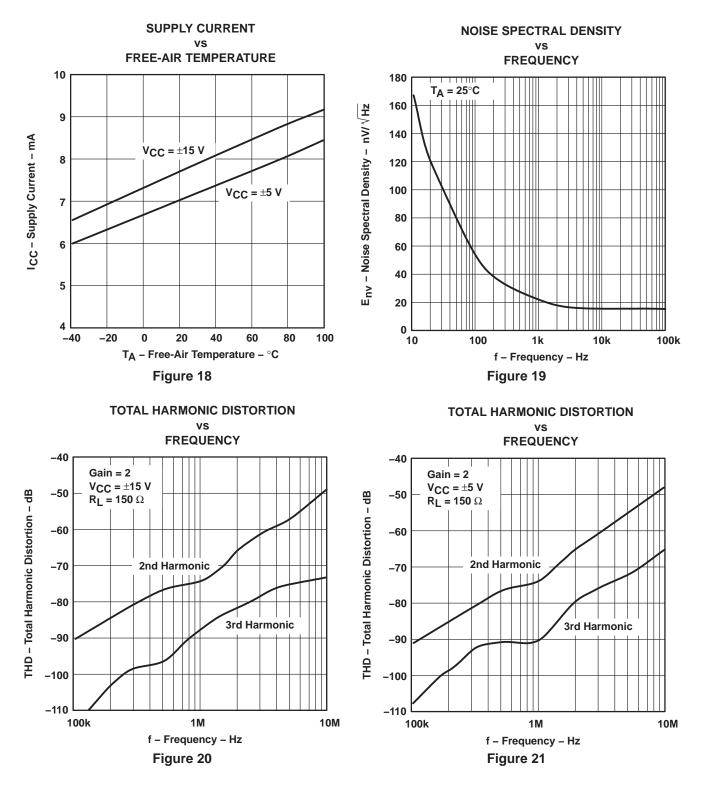


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COMMON-MODE REJECTION RATIO POWER SUPPLY REJECTION RATIO vs vs FREQUENCY FREQUENCY 120 -80 V_{CC} = ±15 V, ±5 V CMRR – Common-Mode Rejection Ratio – dB PSRR – Power Supply Rejection Ratio – dB -70 100 -60 80 -50 60 -40 -30 40 -20 20 -10 V_{CC} = ±15 V, ±5 V 0 0 100k 1M 10M 100M 10k 10k 100k 1M 1k 10M 100M f - Frequency - Hz f - Frequency - Hz Figure 14 Figure 15 POWER SUPPLY REJECTION RATIO **OUTPUT VOLTAGE SWING** vs vs FREE-AIR TEMPERATURE SUPPLY VOLTAGE 90 30 PSRR – Power Supply Rejection Ratio – dB 88 25 Vo(PP) - Output Voltage Swing - V 86 $R_L = 1 k\Omega$ $V_{CC} = -15 V$ 84 20 **R**_L = 150 Ω 82 15 80 V_{CC} = 15 V 78 10 76 5 74 72 0 100 -40 -20 0 20 40 60 80 ±**4** ±6 ±8 ±10 ±12 ±14 ±16 T_A – Free-Air Temperature – °C V_{CC} – Supply Voltage – V Figure 16 Figure 17

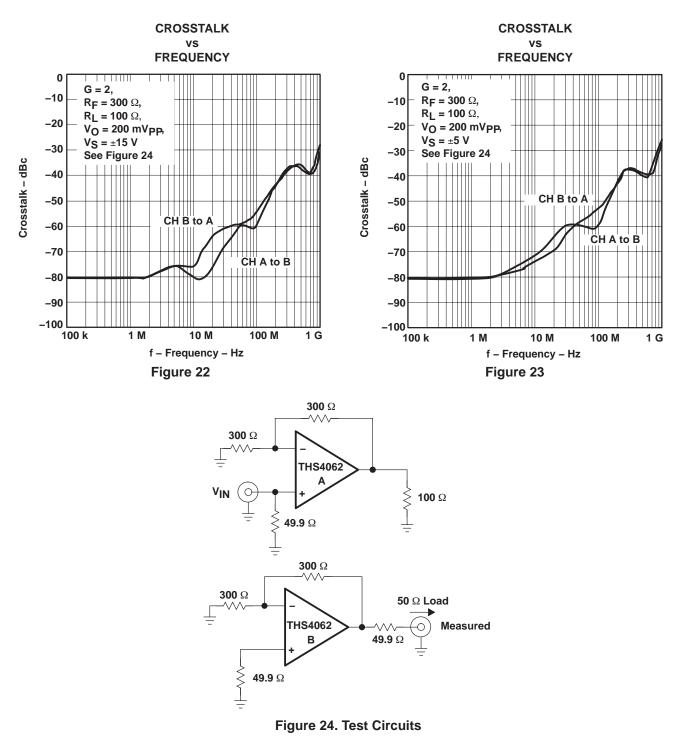


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APPLICATION INFORMATION

theory of operation

The THS406x is a high speed, operational amplifier configured in a voltage feedback architecture. It is built using a 30-V, dielectrically isolated, complementary bipolar process with NPN and PNP transistors possessing f_{TS} of several GHz. This results in an exceptionally high performance amplifier that has a wide bandwidth, high slew rate, fast settling time, and low distortion. A simplified schematic is shown in Figure 25.

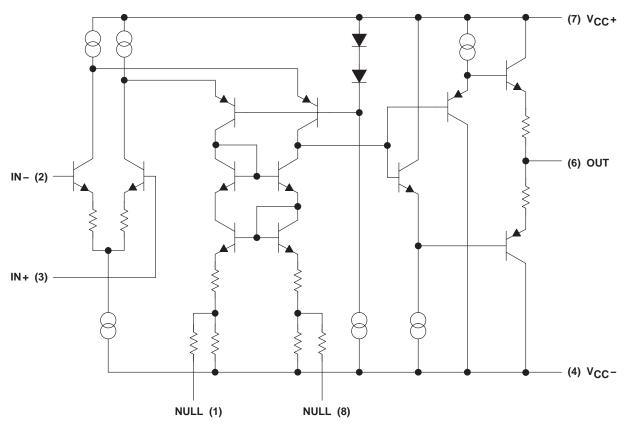


Figure 25. THS4061 Simplified Schematic



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APPLICATION INFORMATION

offset nulling

The THS4061 has very low input offset voltage for a high-speed amplifier. However, if additional correction is required, an offset nulling function has been provided. By placing a potentiometer between terminals 1 and 8 and tying the wiper to the negative supply, the input offset can be adjusted. This is shown in Figure 26.

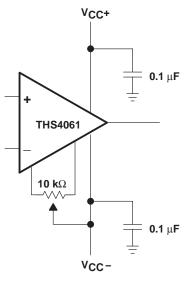


Figure 26. Offset Nulling Schematic

optimizing unity gain response

Internal frequency compensation of the THS406x was selected to provide very wideband performance yet still maintain stability when operated in a noninverting unity gain configuration. When amplifiers are compensated in this manner there is usually peaking in the closed loop response and some ringing in the step response for very fast input edges, depending upon the application. This is because a minimum phase margin is maintained for the G=+1 configuration. For optimum settling time and minimum ringing, a feedback resistor of 270 Ω should be used as shown in Figure 27. Additional capacitance can also be used in parallel with the feedback resistance if even finer optimization is required.

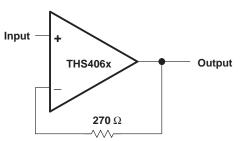


Figure 27. Noninverting, Unity Gain Schematic



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APPLICATION INFORMATION

driving a capacitive load

Driving capacitive loads with high performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS406x has been internally compensated to maximize its bandwidth and slew rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in Figure 28. A minimum value of 20 Ω should work well for most applications. For example, in 75- Ω transmission systems, setting the series resistor value to 75 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.

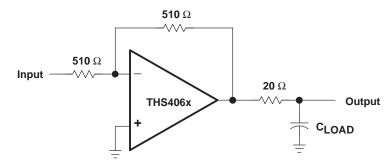


Figure 28. Driving a Capacitive Load

circuit layout considerations

In order to achieve the levels of high frequency performance of the THS406x, it is essential that proper printed-circuit board high frequency design techniques be followed. A general set of guidelines is given below. In addition, a THS406x evaluation board is available to use as a guide for layout or for evaluating the device performance.

- Ground planes It is highly recommended that a ground plane be used on the board to provide all
 components with a low inductive ground connection. However, in the areas of the amplifier inputs and
 output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling Use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-μF capacitor should be placed as close as possible to the supply terminal. As this distances increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets Sockets are not recommended for high-speed operational amplifiers. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements Optimum high frequency performance is achieved when stray
 series inductance has been minimized. To realize this, the circuit layout should be made as compact as
 possible thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting
 input of the amplifier. Its length should be kept as short as possible. This helps to minimize stray capacitance
 at the input of the amplifier.



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APPLICATION INFORMATION

circuit layout considerations (continued)

 Surface-mount passive components – Using surface-mount passive components is recommended for high-frequency amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout, thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

evaluation board

An evaluation board is available for the THS4061 (literature number SLOP226) and THS4062 (literaure number SLOP235). This board has been configured for very low parasitic capacitance in order to realize the full performance of the amplifier. A schematic of the evaluation board is shown in Figure 29. The circuitry has been designed so that the amplifier may be used in either an inverting or noninverting configuration. To order the evaluation board contact your local TI sales office or distributor. For more detailed information, refer to the *THS4061 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU040)

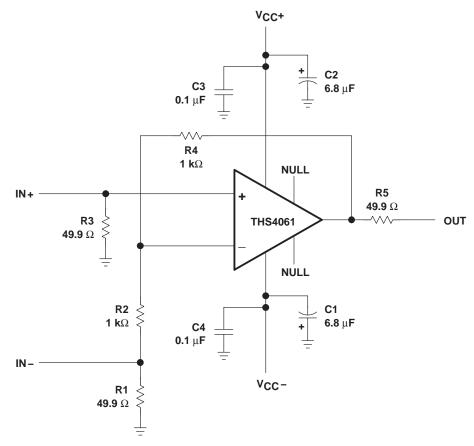


Figure 29. THS4061 Evaluation Board Schematic





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9960101Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9960101Q2A THS4061MFKB	Samples
5962-9960101QPA	ACTIVE	CDIP	JG	8	50	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9960101QPA THS4061M	Samples
THS4061CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4061C	Samples
THS4061CDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	0 to 70		Samples
THS4061CDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABS	Samples
THS4061CDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABS	Samples
THS4061CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4061C	Samples
THS4061ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	40611	Samples
THS4061IDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	-40 to 85		Samples
THS4061IDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT	Samples
THS4061IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	40611	Samples
THS4061MFKB	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9960101Q2A THS4061MFKB	Samples
THS4061MJG	ACTIVE	CDIP	JG	8	50	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	THS4061MJG	Samples
THS4061MJGB	ACTIVE	CDIP	JG	8	50	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9960101QPA THS4061M	Samples
THS4062CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4062C	Samples
THS4062CDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	0 to 70		Samples
THS4062CDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABM	Samples
THS4062CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4062C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
THS4062ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	40621	Samples
THS4062IDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABN	Samples
THS4062IDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABN	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF THS4061, THS4061M :

• Catalog : THS4061

Military : THS4061M

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



Texas

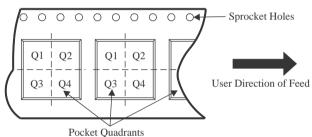
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



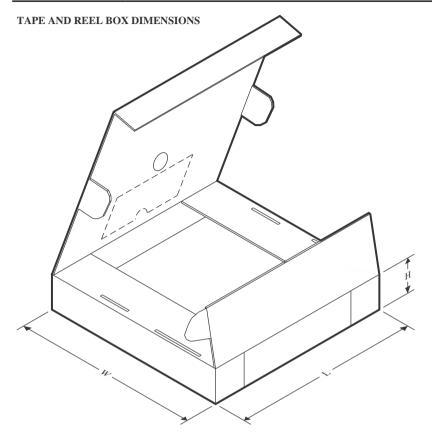
*All dimensions are nomina												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4061CDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4061CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4061IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4061IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4062CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4062IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

5-Dec-2023



*All dimensions	are	nominal	
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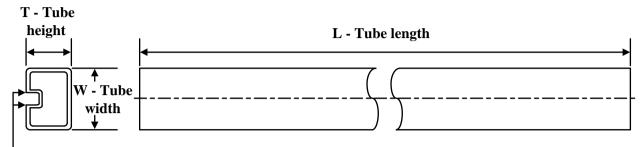
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4061CDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
THS4061CDR	SOIC	D	8	2500	350.0	350.0	43.0
THS4061IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
THS4061IDR	SOIC	D	8	2500	350.0	350.0	43.0
THS4062CDR	SOIC	D	8	2500	350.0	350.0	43.0
THS4062IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0

TEXAS INSTRUMENTS

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TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-9960101Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
THS4061CD	D	SOIC	8	75	505.46	6.76	3810	4
THS4061ID	D	SOIC	8	75	505.46	6.76	3810	4
THS4061MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
THS4062CD	D	SOIC	8	75	505.46	6.76	3810	4
THS4062ID	D	SOIC	8	75	505.46	6.76	3810	4

FK 20

8.89 x 8.89, 1.27 mm pitch

GENERIC PACKAGE VIEW

LCCC - 2.03 mm max height

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.

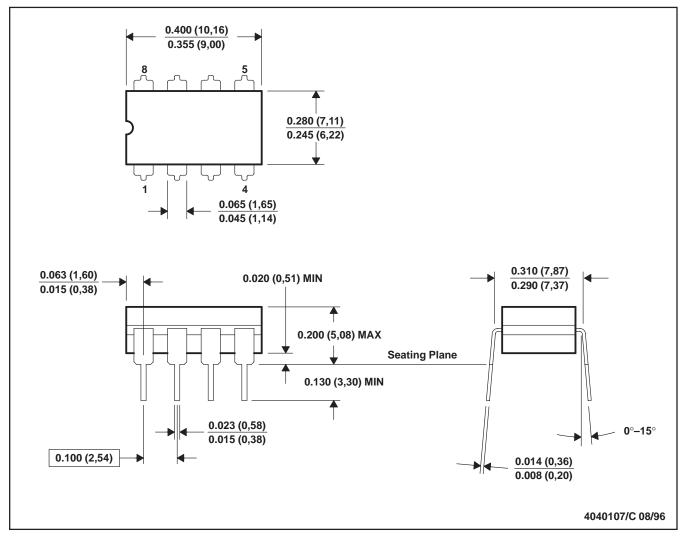


MECHANICAL DATA

MCER001A - JANUARY 1995 - REVISED JANUARY 1997



CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8



GENERIC PACKAGE VIEW

PowerPAD VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

3 x 3, 0.65 mm pitch

DGN 8

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





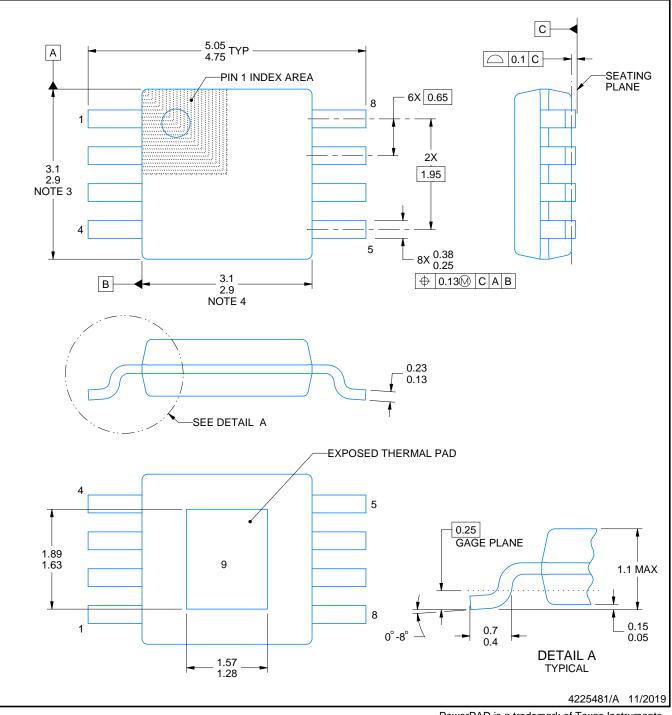
4225482/A

DGN0008D

PACKAGE OUTLINE

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



PowerPAD is a trademark of Texas Instruments.

DGN0008D

EXAMPLE BOARD LAYOUT

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
- on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.

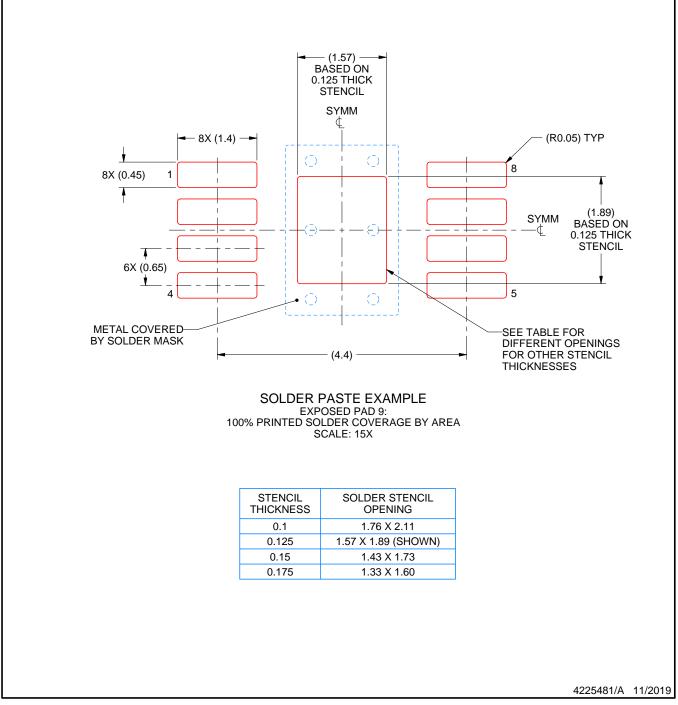


DGN0008D

EXAMPLE STENCIL DESIGN

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



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